Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass and metal
Overall Length:
0.405 inches
Overall Diameter:
0.424 inches
Mounting Facility Quantity:
1
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-4
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
600.0 reverse voltage, peak
Current Rating Per Characteristic:
240.00 amperes forward current, average absolute
Maximum Operating Tempurature Per Measurement Point: 150.0 degrees celsius case
Special Features:
Item must comply with rgmt of desc production standard no. L01402
Thread Series Designator:
Unf
Terminal Type And Quantity:
1 threaded stud and 1 tab, solder lug
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0